

MGBR40U45C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

DESCRIPTION

The UTC **MGBR40U45C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

FEATURES

* Ultra low forward voltage drop* High switching speed

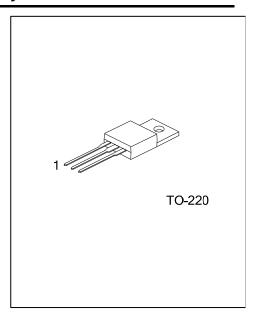
SYMBOL

ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR40U45CL-TA3-T	MGBR40U45CG-TA3-T	TO-220	Α	К	А	Tube	

Note: Pin Assignment: A: Anode, K: Cathode

MGBR40U45C <u>L-TA3-T</u> (1)Pac	king Type	(1) T: Tube
(2)Pac	kage Type	(2) TA3: TO-220
(3)Lea	d Free	(3) L: Lead Free, G: Halogen Free



■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%

Tor capacitance load, derate current by 2070.				
PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V _{RM}	45	V
Working Peak Reverse Voltage		V _{RWM}	45	V
Peak Repetitive Reverse Voltage		V _{RRM}	45	V
Average Destified Output Current Per Device	Per Leg	- I _O	20	А
Average Rectified Output Current Per Device	Total		40	А
Non-Repetitive Peak Forward Surge Current 8. Single Half Sine-Wave Superimposed on Rated		I _{FSM}	360	А
Operating Junction Temperature		ΤJ	-65~+150	°C
Storage Temperature		T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL CHARACTERISTICS (PER LEG)

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ _{JC}	2	°C/W

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA	45			V
Forward Voltage Drop		I _F =20A, T _J =25°C			0.45	V
		I _F =20A, TJ=125°C			0.40	V
Leakage Current (Note 1)	RM	V _R =45V, T _J =25°C			500	μA
		V _R =45V, T _J =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



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